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Kind regards,

Team Nexperia

1PS70SB14

Dual Schottky barrier diode

17 December 2012

Product data sheet

1. General description

Dual Planar Schottky barrier diode in series configuration with an integrated guard ring for stress protection, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

3. Applications

- Ultra high-speed switching
- Line termination
- Voltage clamping
- Reverse polarity protection

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per diode	Per diode							
I _F	forward current			-	-	200	mA	
V _R	reverse voltage			-	-	30	V	
Per diode								
V _F	forward voltage	I _F = 10 mA; T _{amb} = 25 °C		-	-	400	mV	





Dual Schottky barrier diode

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode (diode1)	<u> </u>	K1, A2
2	K2	cathode (diode2)		A1 F K2
3	K1, A2	cathode (diode1) and anode (diode2)	1	aaa-004973

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
1PS70SB14	SC-70	plastic surface-mounted package; 3 leads	SOT323		

7. Marking

Table 4. Marking codes

Type number	Marking code
	[1]
1PS70SB14	7%4

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_R	reverse voltage		-	30	V
I _F	forward current		-	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	-	300	mA
I _{FSM}	non-repetitive peak forward current	t_p < 10 ms; $T_{j(init)}$ = 25 °C	-	600	mA
P _{tot}	total power dissipation	T _{amb} < 25 °C	-	200	mW
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	150	°C

1PS70SB14

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Dual Schottky barrier diode

Symbol	Parameter	Conditions	Min	Max	Unit
T _{stg}	storage temperature		-65	150	°C

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W

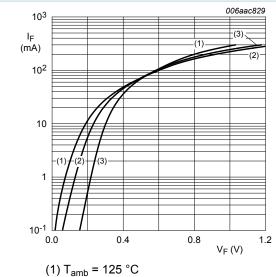
^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V _F	forward voltage	I _F = 0.1 mA; T _{amb} = 25 °C	-	-	240	mV
		I _F = 1 mA; T _{amb} = 25 °C	-	-	320	mV
		I _F = 10 mA; T _{amb} = 25 °C	-	-	400	mV
		I_F = 30 mA; T_{amb} = 25 °C	-	-	500	mV
		I _F = 100 mA; T _{amb} = 25 °C	-	-	800	mV
I _R	reverse current	V_R = 25 V; pulsed; t_p = 300 µs; δ = 0.02; T_{amb} = 25 °C	-	-	2	μΑ
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _{amb} = 25 °C	-	-	10	pF

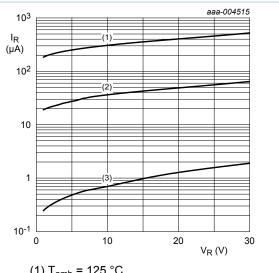
Dual Schottky barrier diode



(2)
$$T_{amb}$$
 = 85 °C

(3)
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 1. Forward current as a function of forward voltage; typical values

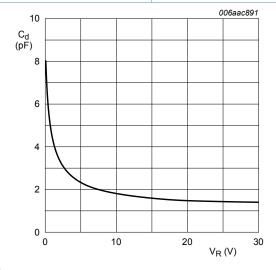


(1)
$$T_{amb} = 125 \, ^{\circ}C$$

(2)
$$T_{amb} = 85 \, ^{\circ}C$$

$$(3) T_{amb} = 25 °C$$

Fig. 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \,^{\circ}\text{C}; f = 1 \,\text{MHz}$

Diode capacitance as a function of reverse voltage; typical values

11. Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

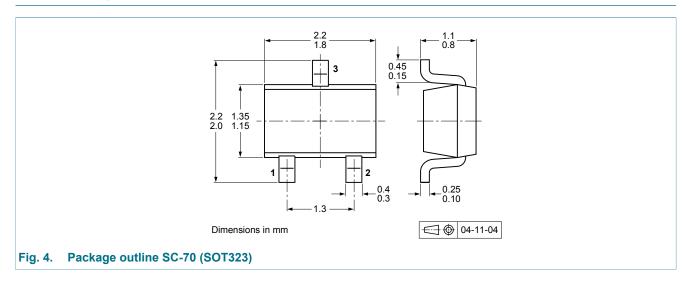
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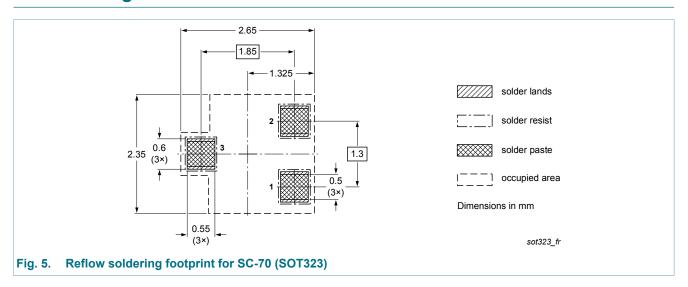
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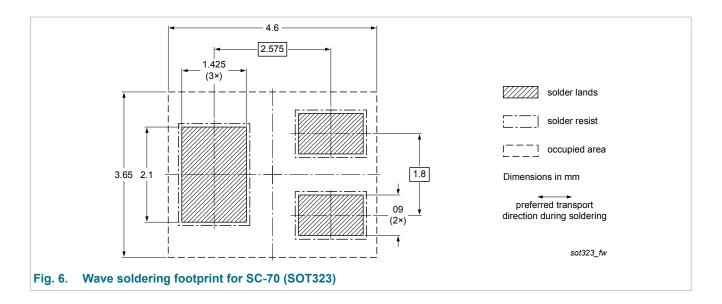
12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
1PS70SB14 v.2	20121217	Product data sheet	-	1PS70SB10_14_15_16 v.1
Modifications:	of NXP Semiconduct Legal texts have be Sections 1 to 3 upde Section 4 "Quick red Section 6 "Ordering Section 7 "Marking" Table 5 "Limiting va Figues 1, 2 and 3 updes Section 11 "Test info	en adapted to the new co ated ference data" added information" added updated lues": ambient temperatu pdated ormation" added ed by minimized package ng" added	ompany name where app re T _{amb} and junction tem	ropriate.
1PS70SB10_14_15_16 v.1	19990426	Product data sheet	-	-

6/9

Dual Schottky barrier diode

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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1PS70SB14

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Dual Schottky barrier diode

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Dual Schottky barrier diode

16. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	2
9	Thermal characteristics	3
10	Characteristics	3
11	Test information	4
11.1	Quality information	
12	Package outline	5
13	Soldering	5
14	Revision history	6
15	Legal information	7
15.1	Data sheet status	7
15.2	Definitions	7
15.3	Disclaimers	7
15.4	Trademarks	8

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